



America Semiconductor

Silicon Bridge Rectifier

KBU6J thru KBU6M

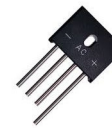
$V_{RRM} = 50\text{ V} - 1000\text{ V}$

$I_F = 6\text{ A}$

Features

- Types up to 1000 V V_{RRM}
- Ideal for printed circuit board
- High forward surge current capability
- High temperature soldering guaranteed 250°C/ 10 seconds
- Plastic package has Underwriters Laboratory Flammability Classification 94V-0

KBU Package



Mechanical Data

Case: Molded plastic body
 Mounting position: Any
 Terminals: Plated leads, solderable per MIL-STD-750, Method 2026
 Mounting torque: 5 inch-lbs max

Maximum ratings, at $T_j = 25\text{ °C}$, unless otherwise specified

Parameter	Symbol	Conditions	KBU6J	KBU6K	KBU6M	Unit
Repetitive peak reverse voltage	V_{RRM}		600	800	1000	V
RMS reverse voltage	V_{RMS}		420	560	700	V
DC blocking voltage	V_{DC}		600	800	1000	V
Continuous forward current	I_F	$T_C \leq 100\text{ °C}$	6	6	6	A
Surge non-repetitive forward current, Half Sine Wave	$I_{F,SM}$	$T_C = 25\text{ °C}$, $t_p = 8.3\text{ ms}$	250	250	250	A
Operating temperature	T_j		-55 to 150	-55 to 150	-55 to 150	°C
Storage temperature	T_{stg}		-55 to 150	-55 to 150	-55 to 150	°C

Electrical characteristics, at $T_j = 25\text{ °C}$, unless otherwise specified

Parameter	Symbol	Conditions	KBU6J	KBU6K	KBU6M	Unit
Diode forward voltage	V_F	$I_F = 6\text{ A}$, $T_j = 25\text{ °C}$	1	1	1	V
Reverse current	I_R	$V_R = 50\text{ V}$, $T_j = 25\text{ °C}$	10	10	10	μA
		$V_R = 50\text{ V}$, $T_j = 100\text{ °C}$	500	500	500	



